RJP1CS26DWA / RJP1CS26DWS

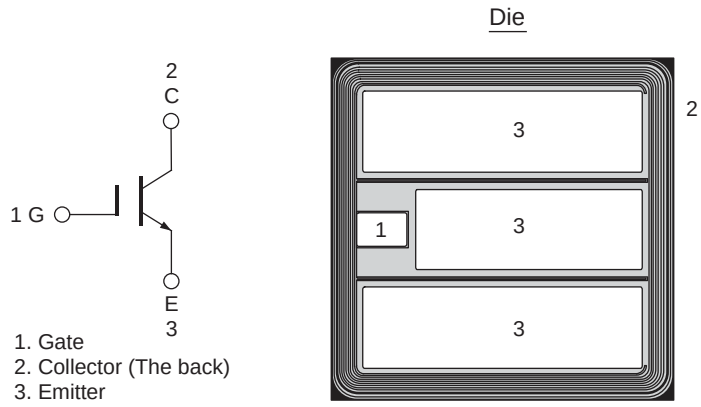
1250V - 100A - IGBT
Application: Inverter

R07DS1304EJ0100
Rev.1.00
Sep 30, 2015

Features

- Renesas generation 7th Trench IGBT
- Low collector to emitter saturation voltage
  $V_{CE(sat)}$ = 1.55 V typ. (at I_C = 100 A, V_{GE} = 15 V, Tc = 25°C)
- Moderate speed switching
- Short circuit withstands time (10 μs min.)

Outline



Absolute Maximum Ratings

(Tc = 25°C unless otherwise noted)

Item		Symbol	Ratings	Unit
Collector to emitter voltage		V_{CES}	1250	V
Gate to emitter voltage		V_{GES}	±30	V
Collector current	Tc = 25°C	I_C	200	A
	Tc = 100°C	I_C	100	A
Junction temperature		Tj	175 Note1	°C

Notes: 1. Please use this device in the thermal conditions where the junction temperature does not exceed 175°C.
IGBT Application Note is disclosed about reliability test and application condition up to Tj = 175°C.

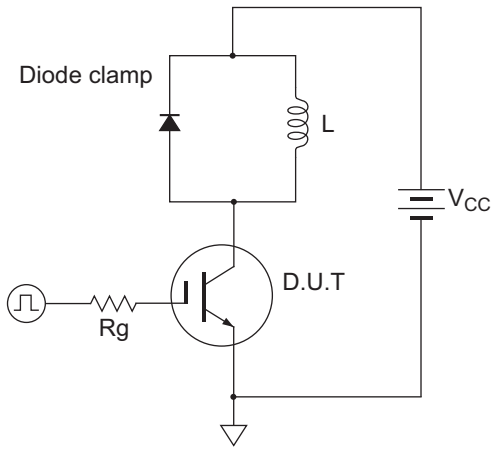
Electrical Characteristics (These data are actual measurement values in an evaluation package.)

(Tc = 25°C unless otherwise noted)

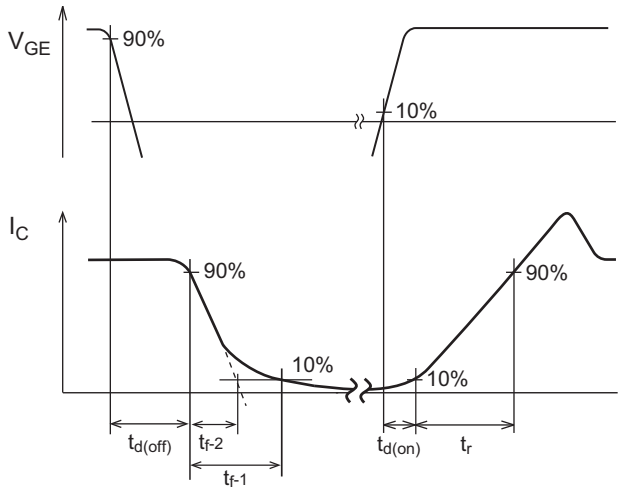
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Zero gate voltage collector current	I_{CES}	—	—	1	μA	V_{CE} = 1250 V, V_{GE} = 0
Gate to emitter leak current	I_{GES}	—	—	±1	μA	V_{GE} = ±30 V, V_{CE} = 0
Gate to emitter cutoff voltage	$V_{GE(off)}$	5.0	—	6.8	V	V_{CE} = 10 V, I_C = 3.3 mA
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	1.55	2.0	V	I_C = 100 A, V_{GE} = 15 V Note2
Input capacitance	Cies	—	9.8	—	nF	V_{CE} = 25 V V_{GE} = 0 f = 1 MHz
Output capacitance	Coes	—	0.27	—	nF	
Reveres transfer capacitance	Cres	—	0.21	—	nF	
Total gate charge	Qg	—	630	—	nC	V_{GE} = 15 V V_{CE} = 600 V I_C = 100 A
Gate to emitter charge	Qge	—	105	—	nC	
Gate to collector charge	Qgc	—	350	—	nC	
Switching time Note3	$t_{d(on)}$	—	95	—	ns	V_{CC} = 600 V I_C = 100 A V_{GE} =±15 V Rg = 15 Ω, Tc = 150 °C Inductive load
	t_r	—	60	—	ns	
	$t_{d(off)}$	—	580	—	ns	
	t_{f-1}	—	280	—	ns	
	t_{f-2}	—	150	—	ns	
Short circuit withstand time Note4	t_{sc}	10	—	—	μs	V_{CC} ≤ 720 V , V_{GE} = 15 V Tc = 150 °C

Notes: 2. Pulse test.
3. Switching time test circuit and waveform are shown below.
4. Verified by design

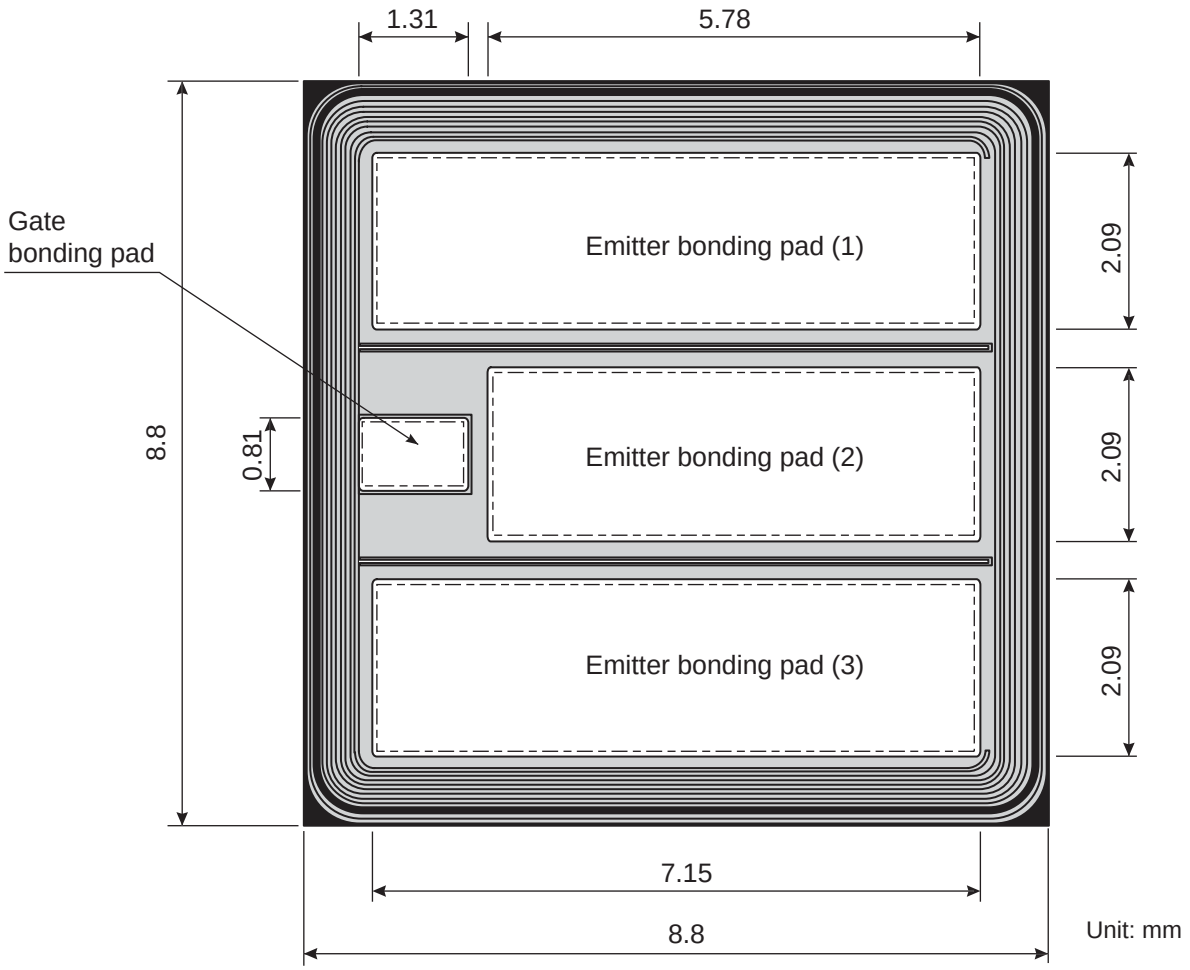
Switching Time Test Circuit



Waveform



Die Dimension



Note 1.

Illustration	Definition
Part of white	Al pattern
Part of dotted line	Bonding area
Part of gray	Final passivation

Note 2. The back of the chip is processed with Au evaporation.

Note 3. Recognition, target and any other patterns which are not related to IGBT operation, may be changed without notice.

Ordering Information

Orderable Part Number	Shipment form
RJP1CS26DWA-80#W0	Unsawn wafer
RJP1CS26DWS-80#W0	Sawn wafer

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